ALPHA & OMEGA SEMICONDUCTOR

AOK40N30

300V,40A N-Channel MOSFET

General Description

The AOK40N30 is fabricated using an advanced high voltage MOSFET process that is designed to deliver high levels of performance and robustness in popular AC-DC applications.By providing low $R_{DS(on)}$, C_{iss} and C_{rss} along with guaranteed avalanche capability this part can be adopted quickly into new and existing offline power supply designs.

For Halogen Free add "L" suffix to part number: AOK40N30L

Product Summary

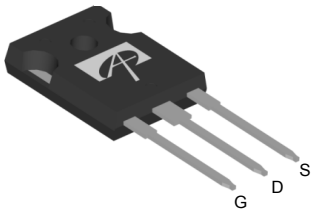
V_{DS}	350@150℃
I_D (at V_{GS}=10V)	40A
$R_{DS(ON)}$ (at V_{GS}=10V)	< 0.085Ω

100% UIS Tested
100% R_g Tested

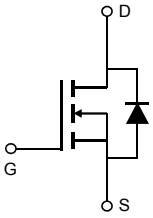
RoHS Compliant

Top View

TO-247



AOK40N30



Absolute Maximum Ratings T_A=25°C unless otherwise noted

Parameter		Symbol	AOK40N30	Units
Drain-Source Voltage		V_{DS}	300	V
Gate-Source Voltage		V_{GS}	±30	V
Continuous Drain Current	T_C=25°C	I_D	40	A
	T_C=100°C		25	
Pulsed Drain Current [C]		I_{DM}	135	
Avalanche Current [C]		I_{AR}	8.5	A
Repetitive avalanche energy [C]		E_{AR}	1083	mJ
Single plused avalanche energy [G]		E_{AS}	2167	mJ
Peak diode recovery dv/dt		dv/dt	5	V/ns
Power Dissipation [B]	T_C=25°C	P_D	357	W
	Derate above 25°C		2.9	W/ °C
Junction and Storage Temperature Range		T_J, T_{STG}	-55 to 150	°C
Maximum lead temperature for soldering purpose, 1/8" from case for 5 seconds		T_L	300	°C

Thermal Characteristics

Parameter	Symbol	AOK40N30	Units
Maximum Junction-to-Ambient [A,D]	$R_{\theta JA}$	40	°C/W
Maximum Case-to-sink [A]	$R_{\theta CS}$	0.5	°C/W
Maximum Junction-to-Case	$R_{\theta JC}$	0.35	°C/W

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
STATIC PARAMETERS						
BV_{DSS}	Drain-Source Breakdown Voltage	I_D=250µA, V_{GS}=0V, T_J=25°C	300			V
		I_D=250µA, V_{GS}=0V, T_J=150°C		350		
BV_{DSS} /ΔTJ	Zero Gate Voltage Drain Current	ID=250µA, VGS=0V		0.28		V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS}=300V, V_{GS}=0V			1	µA
		V_{DS}=240V, T_J=125°C			10	
I_{GSS}	Gate-Body leakage current	V_{DS}=0V, V_{GS}=±30V			±100	nA
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=5V, I_D=250µA	2.9	3.5	4.1	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance	V_{GS}=10V, I_D=20A		0.065	0.085	Ω
g_{FS}	Forward Transconductance	V_{DS}=40V, I_D=20A		32		S
V_{SD}	Diode Forward Voltage	I_S=1A,V_{GS}=0V		0.7	1	V
I_S	Maximum Body-Diode Continuous Current				40	A
I_{SM} [C]	Maximum Body-Diode Pulsed Current				135	A
DYNAMIC PARAMETERS						
C_{iss}	Input Capacitance	V_{GS}=0V, V_{DS}=25V, f=1MHz	2170	2718	3270	pF
C_{oss}	Output Capacitance		280	405	530	pF
C_{rss}	Reverse Transfer Capacitance		18	31	45	pF
R_g	Gate resistance	V_{GS}=0V, V_{DS}=0V, f=1MHz	0.6	1.4	2.1	Ω
SWITCHING PARAMETERS						
Q_g	Total Gate Charge	V_{GS}=10V, V_{DS}=240V, I_D=40A	48	60	72	nC
Q_{gs}	Gate Source Charge			13		nC
Q_{gd}	Gate Drain Charge			21		nC
$t_{D(on)}$	Turn-On DelayTime	V_{GS}=10V, V_{DS}=150V, I_D=40A, R_G=25Ω		54		ns
t_r	Turn-On Rise Time			166		ns
$t_{D(off)}$	Turn-Off DelayTime			152		ns
t_f	Turn-Off Fall Time			118		ns
t_{rr}	Body Diode Reverse Recovery Time	I_F=40A,dI/dt=100A/µs,V_{DS}=100V	220	275	330	ns
Q_{rr}	Body Diode Reverse Recovery Charge	I_F=40A,dI/dt=100A/µs,V_{DS}=100V	6.5	8.2	10	µC

A. The value of $R_{\theta JA}$ is measured with the device in a still air environment with T_A=25° C.
B. The power dissipation P_D is based on $T_{J(MAX)}$=150° C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
C. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150° C, Ratings are based on low frequency and duty cycles to keep initial T_J =25° C.
D. The $R_{\theta JA}$ is the sum of the thermal impedance from junction to case $R_{\theta JC}$ and case to ambient.
E. The static characteristics in Figures 1 to 6 are obtained using <300 µs pulses, duty cycle 0.5% max.
F. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of $T_{J(MAX)}$=150° C. The SOA curve provides a single pulse rating.
G. L=60mH, I_{AS}=8.5A, V_{DD}=150V, R_G=25Ω, Starting T_J=25° C

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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

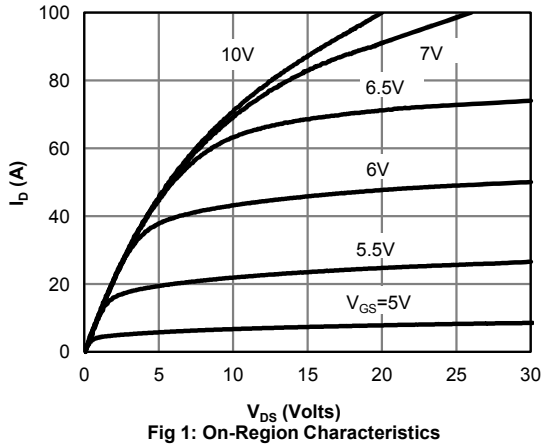


Fig 1: On-Region Characteristics

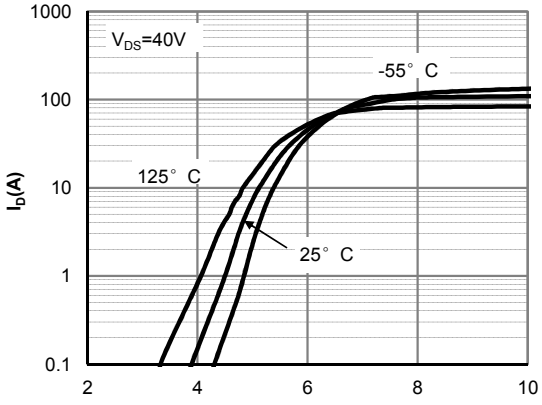


Figure 2: Transfer Characteristics

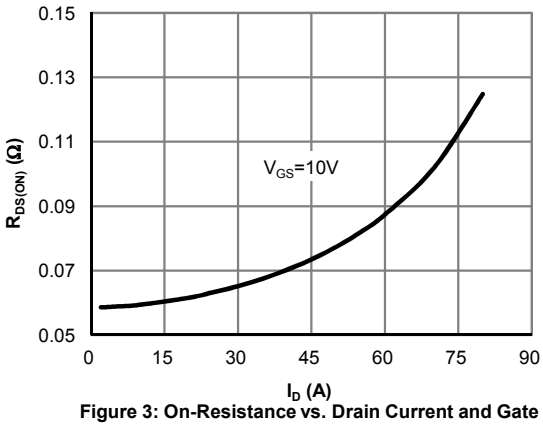


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

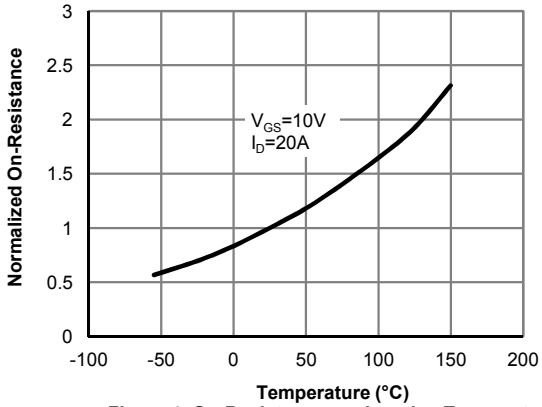


Figure 4: On-Resistance vs. Junction Temperature

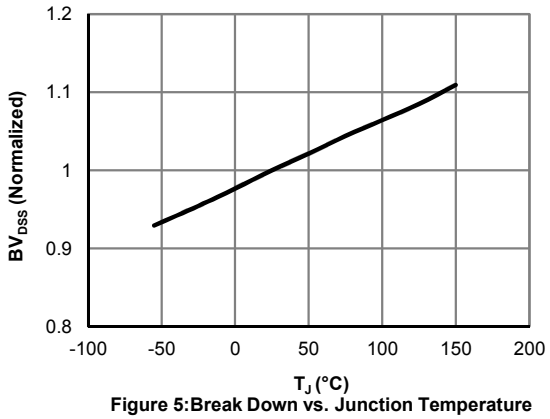


Figure 5:Break Down vs. Junction Temperature

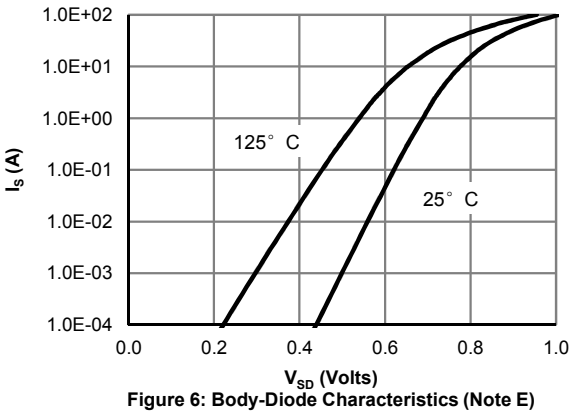


Figure 6: Body-Diode Characteristics (Note E)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

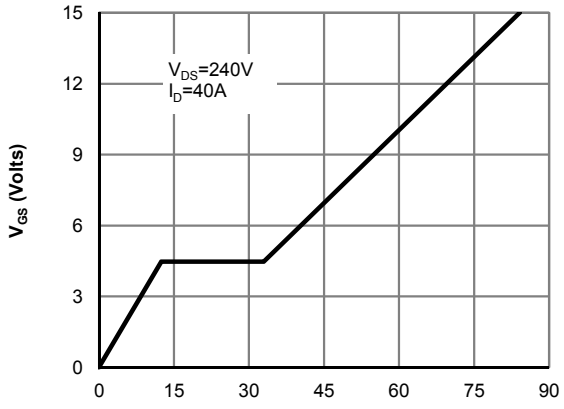


Figure 7: Gate-Charge Characteristics

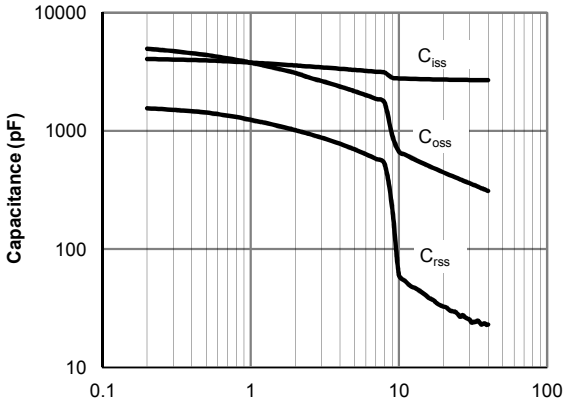


Figure 8: Capacitance Characteristics

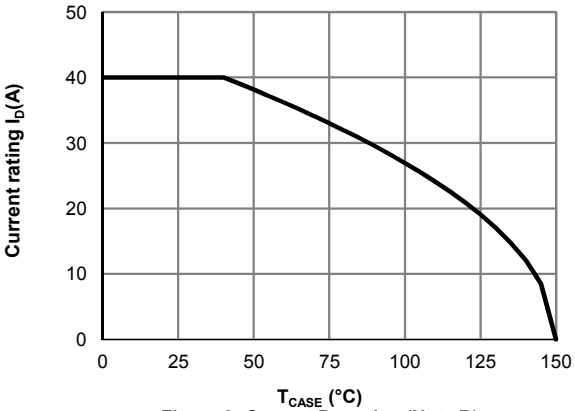


Figure 9: Current De-rating (Note B)

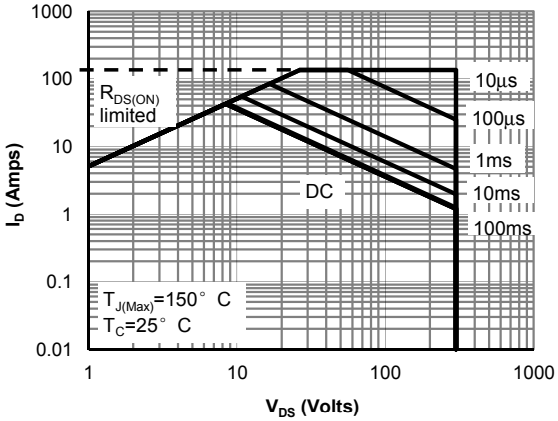


Figure 10: Maximum Forward Biased Safe Operating Area for AOK40N30 (Note F)

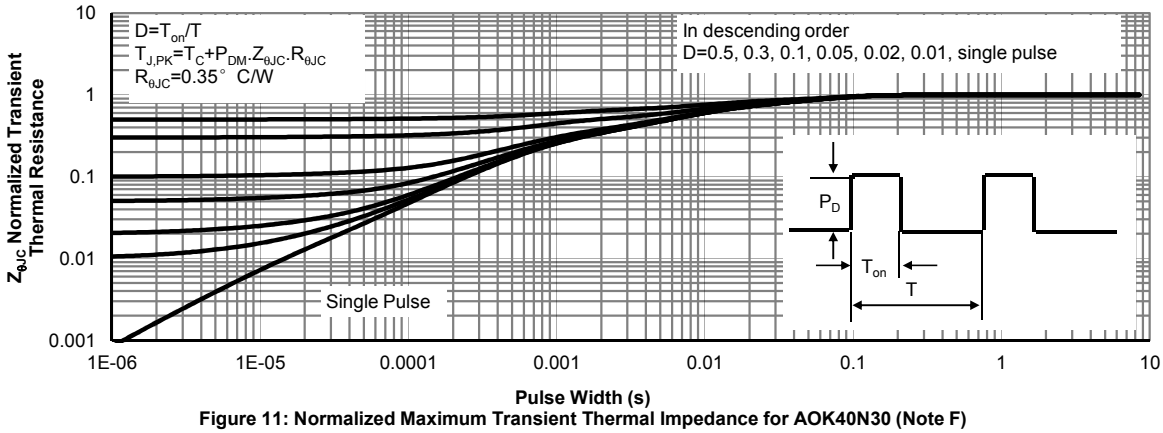
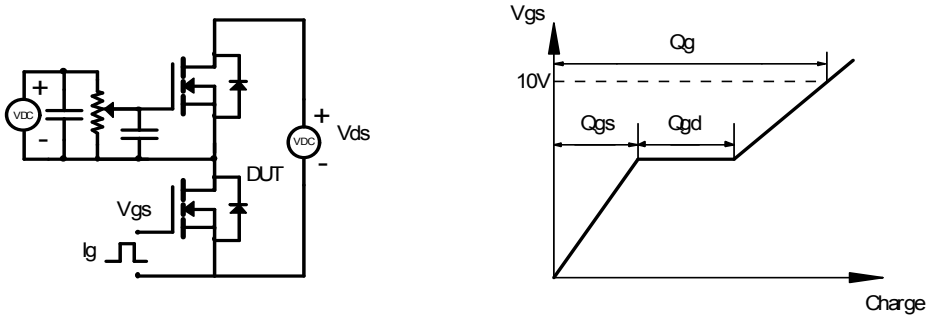
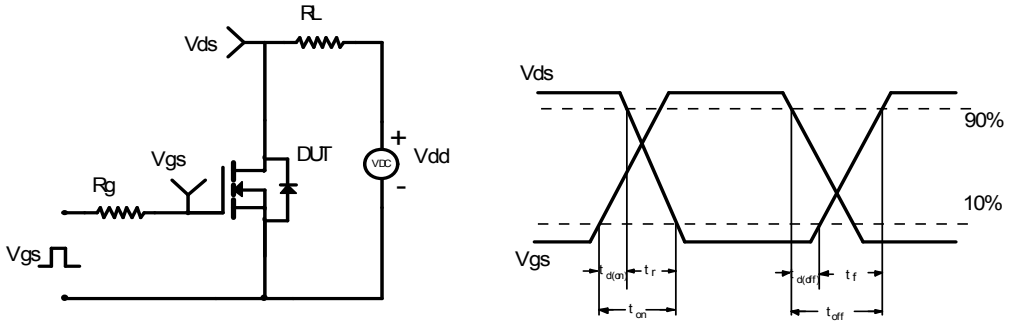


Figure 11: Normalized Maximum Transient Thermal Impedance for AOK40N30 (Note F)

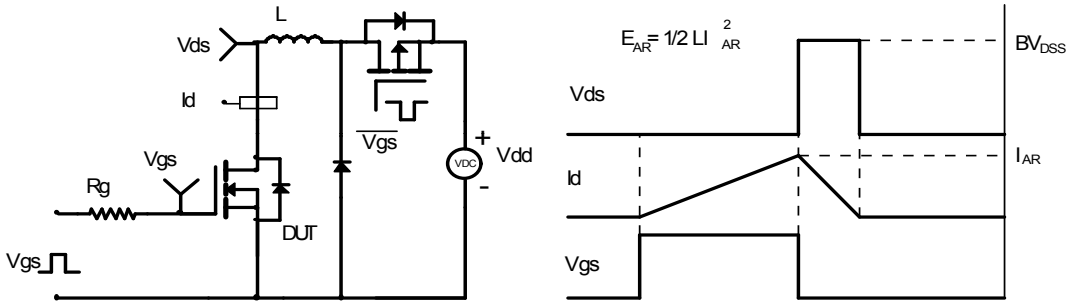
Gate Charge Test Circuit & Waveform



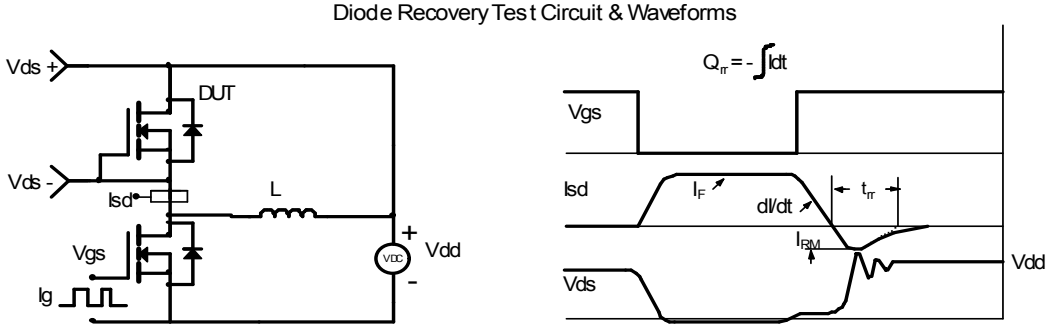
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